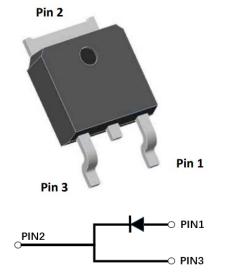


YJD106506DQG2

Silicon Carbide Schottky Diode

| V _{RRM} | 650V |
|------------------------|------|
| I _F (135°C) | 11A |
| Qc | 25nC |



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery voltage
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, automotive battery chargers.

Mechanical Data

- Package: TO-252 Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- Terminals: Tin plated leads
- Polarity: As marked

■Maximum Ratings (T_c=25 °C Unless otherwise specified)

| PARAMTETER | SYMBOL | UNIT | VALUE |
|--|----------------------------------|------------------|-------------|
| Device marking code | | | D106506DQG2 |
| Reverse voltage (repetitive peak) @ T _j =25°C | V _{RRM} | V | 650 |
| Reverse voltage (Surge Peak) @ T _j =25°C | V _{RSM} | V | 650 |
| Reverse voltage (DC) @ T _j =25°C | V _{DC} | V | 650 |
| Continuous forward current @ T _c =25°C | | | 23 |
| Continuous forward current @ T _c =135°C | IF | А | 11 |
| Continuous forward current @ T _c =160°C | | | 6 |
| Non-repetitive peak forward surge current @ T _c =25°C, tp=10ms, Half Sine Wave | I _{FSM} | А | 65 |
| Power Dissipation@ T₀=25°C | Ρτοτ | w | 100 |
| Power Dissipation@ T _c =110°C | FTOT | vv | 43 |
| i²t Value@ Tc=25°C ,tp=10ms | ∫i²dt | A ² S | 21 |
| Operating junction and Storage temperature range | T _j ,T _{stg} | °C | -55 to +175 |

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Electrical Characteristics

| PARAMTETER | SYMBOL | UNIT | TEST CONDITIONS | Тур. | Max. |
|---------------------------|----------------|------|--|------|------|
| Forward voltage drop | V _F | v | I _F =6A, T _j =25°C | 1.31 | 1.5 |
| | | | I _F =6A, T _j =175°C | 1.65 | - |
| | | μΑ | V _R =650V, T _j =25°C | 0.5 | 25 |
| Reverse leakage current | I _R | | V _R =650V, T _j =175°C | 5 | - |
| Total capacitive charge | Qc | nC | $V_{\text{R}}\text{=}400\text{V},T_{j}\text{=}25^{\circ}\text{C}$, $Q\text{C}\text{=}\int_{0}^{V\text{R}}\text{C}(\text{V})\text{d}\text{V}$ | 25 | - |
| Total capacitance | С | pF | V _R =0V, f=1MHZ | 378 | - |
| | | | V _R =200V, f=1MHZ | 51 | - |
| | | | V _R =400V, f=1MHZ | 49 | - |
| Capacitance Stored Energy | Ec | μJ | V _R =400V | 3 | - |

■Thermal Characteristics (Ta=25°C Unless otherwise specified)

Figure 1. Forward Characteristics

| PARAMETER | SYMBOL | UNIT | Value |
|--------------------|-------------------|------|-------|
| Thermal resistance | R _{øJ-C} | °C W | 1.49 |

■Typical Characteristics

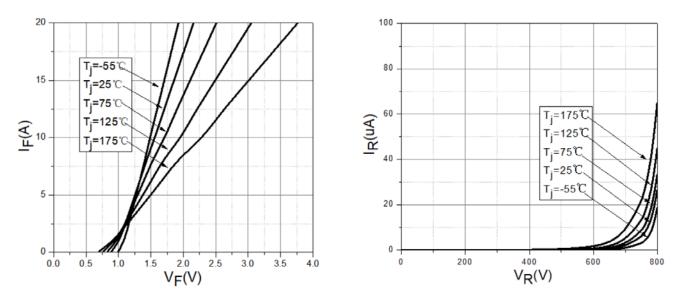


Figure2. Reverse Characteristic

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YJD106506DQG2

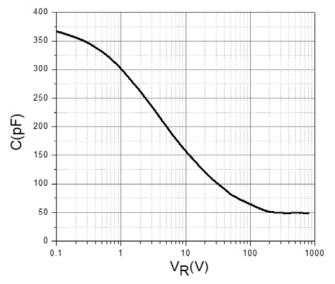
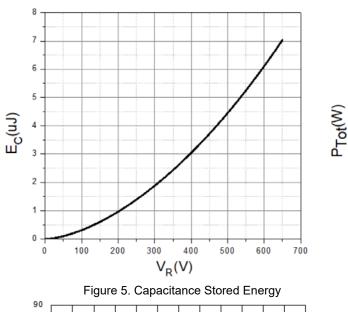
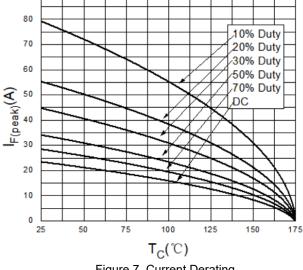
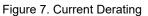


Figure 3. Capacitance vs. Reverse Voltage







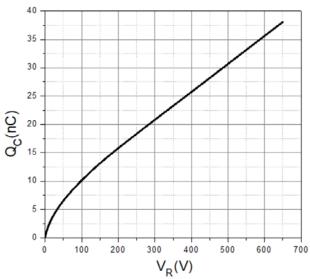
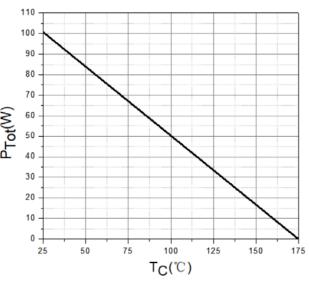
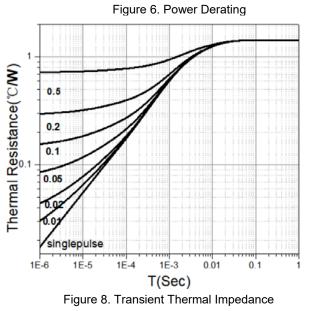


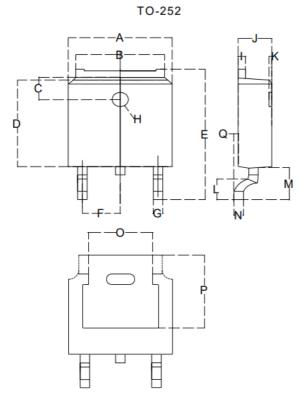
Figure 4. Total Capacitance Charge vs. Reverse Voltage







Outline Dimensions



| TO-252 | | | |
|--------|--------|--------|--|
| Dim | Min | Max | |
| Α | 6.500 | 6.700 | |
| В | 5.100 | 5.460 | |
| С | 1.400 | 1.800 | |
| D | 6.000 | 6.200 | |
| E | 10.000 | 10.400 | |
| F | 2.166 | 2.366 | |
| G | 0.660 | 0.860 | |
| н | Ф1.050 | Ф1.350 | |
| I | 0.460 | 0.580 | |
| J | 2.200 | 2.400 | |
| К | 0 | 0.300 | |
| L | 0.890 | 2.290 | |
| М | 2.730 | 3.080 | |
| N | 0.430 | 0.580 | |
| 0 | 4.20 | 4.95 | |
| Р | 5.15 | 5.45 | |
| Q | 0 | 0.2 | |

Dimensions in millimeters

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YJD106506DQG2

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